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Intel - EPF10K100ABI356-3 Datasheet



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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Det	ai	Is

Details	
Product Status	Obsolete
Number of LABs/CLBs	624
Number of Logic Elements/Cells	4992
Total RAM Bits	24576
Number of I/O	274
Number of Gates	158000
Voltage - Supply	3V ~ 3.6V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 85°C (TA)
Package / Case	356-LBGA
Supplier Device Package	356-BGA (35x35)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epf10k100abi356-3

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Notes to tables:

- (1)FLEX 10K and FLEX 10KA device package types include plastic J-lead chip carrier (PLCC), thin quad flat pack (TQFP), plastic quad flat pack (PQFP), power quad flat pack (RQFP), ball-grid array (BGA), pin-grid array (PGA), and FineLine BGA[™] packages.
- This option is supported with a 256-pin FineLine BGA package. By using SameFrame pin migration, all FineLine (2) BGA packages are pin compatible. For example, a board can be designed to support both 256-pin and 484-pin FineLine BGA packages. The Altera software automatically avoids conflicting pins when future migration is set.

General Description

Altera's FLEX 10K devices are the industry's first embedded PLDs. Based on reconfigurable CMOS SRAM elements, the Flexible Logic Element MatriX (FLEX) architecture incorporates all features necessary to implement common gate array megafunctions. With up to 250,000 gates, the FLEX 10K family provides the density, speed, and features to integrate entire systems, including multiple 32-bit buses, into a single device.

FLEX 10K devices are reconfigurable, which allows 100% testing prior to shipment. As a result, the designer is not required to generate test vectors for fault coverage purposes. Additionally, the designer does not need to manage inventories of different ASIC designs; FLEX 10K devices can be configured on the board for the specific functionality required.

Table 6 shows FLEX 10K performance for some common designs. All performance values were obtained with Synopsys DesignWare or LPM functions. No special design technique was required to implement the applications; the designer simply inferred or instantiated a function in a Verilog HDL, VHDL, Altera Hardware Description Language (AHDL), or schematic design file.

Table 6. FLEX 10K & FLEX 10KA Performance									
Application		urces sed	Performance				Units		
	LEs	EABs	-1 Speed Grade	-2 Speed Grade	-3 Speed Grade	-4 Speed Grade			
16-bit loadable counter (1)	16	0	204	166	125	95	MHz		
16-bit accumulator (1)	16	0	204	166	125	95	MHz		
16-to-1 multiplexer (2)	10	0	4.2	5.8	6.0	7.0	ns		
256×8 RAM read cycle speed (3)	0	1	172	145	108	84	MHz		
256×8 RAM write cycle speed (3)	0	1	106	89	68	63	MHz		

Notes:

(1) The speed grade of this application is limited because of clock high and low specifications.

This application uses combinatorial inputs and outputs. (2)

This application uses registered inputs and outputs. (3)

Altera Corporation

The logic array consists of logic array blocks (LABs). Each LAB contains eight LEs and a local interconnect. An LE consists of a 4-input look-up table (LUT), a programmable flipflop, and dedicated signal paths for carry and cascade functions. The eight LEs can be used to create medium-sized blocks of logic—8-bit counters, address decoders, or state machines—or combined across LABs to create larger logic blocks. Each LAB represents about 96 usable gates of logic.

Signal interconnections within FLEX 10K devices and to and from device pins are provided by the FastTrack Interconnect, a series of fast, continuous row and column channels that run the entire length and width of the device.

Each I/O pin is fed by an I/O element (IOE) located at the end of each row and column of the FastTrack Interconnect. Each IOE contains a bidirectional I/O buffer and a flipflop that can be used as either an output or input register to feed input, output, or bidirectional signals. When used with a dedicated clock pin, these registers provide exceptional performance. As inputs, they provide setup times as low as 1.6 ns and hold times of 0 ns; as outputs, these registers provide clock-to-output times as low as 5.3 ns. IOEs provide a variety of features, such as JTAG BST support, slew-rate control, tri-state buffers, and open-drain outputs.

Figure 1 shows a block diagram of the FLEX 10K architecture. Each group of LEs is combined into an LAB; LABs are arranged into rows and columns. Each row also contains a single EAB. The LABs and EABs are interconnected by the FastTrack Interconnect. IOEs are located at the end of each row and column of the FastTrack Interconnect.





Figure 4. FLEX 10K Embedded Array Block

`EAB Local Interconnect (1)

Note:

 EPF10K10, EPF10K10A, EPF10K20, EPF10K30, EPF10K30A, EPF10K40, EPF10K50, and EPF10K50V devices have 22 EAB local interconnect channels; EPF10K70, EPF10K100, EPF10K100A, EPF10K130V, and EPF10K250A devices have 26. Figure 7 shows how an *n*-bit full adder can be implemented in n + 1 LEs with the carry chain. One portion of the LUT generates the sum of two bits using the input signals and the carry-in signal; the sum is routed to the output of the LE. The register can either be bypassed for simple adders or be used for an accumulator function. The carry chain logic generates the carry-out signal, which is routed directly to the carry-in signal of the next-higher-order bit. The final carry-out signal is routed to an LE, where it can be used as a general-purpose signal.



Figure 7. Carry Chain Operation (n-bit Full Adder)

Figure 12 shows the interconnection of adjacent LABs and EABs with row, column, and local interconnects, as well as the associated cascade and carry chains. Each LAB is labeled according to its location: a letter represents the row and a number represents the column. For example, LAB B3 is in row B, column 3.





I/O Element

An I/O element (IOE) contains a bidirectional I/O buffer and a register that can be used either as an input register for external data that requires a fast setup time, or as an output register for data that requires fast clockto-output performance. In some cases, using an LE register for an input register will result in a faster setup time than using an IOE register. IOEs can be used as input, output, or bidirectional pins. For bidirectional registered I/O implementation, the output register should be in the IOE and, the data input and output enable register should be LE registers placed adjacent to the bidirectional pin. The Compiler uses the programmable inversion option to invert signals from the row and column interconnect automatically where appropriate. Figure 13 shows the bidirectional I/O registers. Table 12 describes the FLEX 10K device supply voltages and MultiVolt I/O support levels.

Devices	Supply Vo	oltage (V)	MultiVolt I/O Sup	port Levels (V)
	V _{CCINT}	V _{CCIO}	Input	Output
FLEX 10K (1)	5.0	5.0	3.3 or 5.0	5.0
	5.0	3.3	3.3 or 5.0	3.3 or 5.0
EPF10K50V (1)	3.3	3.3	3.3 or 5.0	3.3 or 5.0
EPF10K130V	3.3	3.3	3.3 or 5.0	3.3 or 5.0
FLEX 10KA (1)	3.3	3.3	2.5, 3.3, or 5.0	3.3 or 5.0
	3.3	2.5	2.5, 3.3, or 5.0	2.5

Note

(1) 240-pin QFP packages do not support the MultiVolt I/O features, so they do not have separate V_{CCIO} pins.

Power Sequencing & Hot-Socketing

Because FLEX 10K devices can be used in a multi-voltage environment, they have been designed specifically to tolerate any possible power-up sequence. The $V_{\rm CCIO}$ and $V_{\rm CCINT}$ power supplies can be powered in any order.

Signals can be driven into FLEX 10KA devices before and during power up without damaging the device. Additionally, FLEX 10KA devices do not drive out during power up. Once operating conditions are reached, FLEX 10KA devices operate as specified by the user.

IEEE Std. 1149.1 (JTAG) Boundary-Scan Support

All FLEX 10K devices provide JTAG BST circuitry that complies with the IEEE Std. 1149.1-1990 specification. All FLEX 10K devices can also be configured using the JTAG pins through the BitBlaster serial download cable, or ByteBlasterMV parallel port download cable, or via hardware that uses the Jam[™] programming and test language. JTAG BST can be performed before or after configuration, but not during configuration. FLEX 10K devices support the JTAG instructions shown in Table 13.

Notes to tables:

- (1) See the Operating Requirements for Altera Devices Data Sheet.
- (2) Minimum DC input voltage is -0.5 V. During transitions, the inputs may undershoot to -2.0 V for input currents less than 100 mA and periods shorter than 20 ns.
- (3) Numbers in parentheses are for industrial-temperature-range devices.
- (4) Maximum \hat{V}_{CC} rise time is 100 ms. V_{CC} must rise monotonically.
- (5) Typical values are for $T_A = 25^\circ \text{ C}$ and $V_{CC} = 5.0 \text{ V}$.
- (6) These values are specified under the Recommended Operation Condition shown in Table 18 on page 45.
- (7) The I_{OH} parameter refers to high-level TTL or CMOS output current.
- (8) The I_{OL} parameter refers to low-level TTL or CMOS output current. This parameter applies to open-drain pins as well as output pins.
- (9) This value is specified for normal device operation. The value may vary during power-up.
- (10) Capacitance is sample-tested only.

Figure 20 shows the typical output drive characteristics of FLEX 10K devices with 5.0-V and 3.3-V V_{CCIO} . The output driver is compliant with the 5.0-V *PCI Local Bus Specification, Revision 2.2* (for 5.0-V V_{CCIO}).

Figure 20. Output Drive Characteristics of FLEX 10K Devices



Tables 22 through 25 provide information on absolute maximum ratings, recommended operating conditions, DC operating conditions, and capacitance for EPF10K50V and EPF10K130V devices.

Table 22. EPF10K50V & EPF10K130V Device Absolute Maximum Ratings Note (1)						
Symbol	Parameter	Conditions	Min	Max	Unit	
V _{CC}	Supply voltage	With respect to ground (2)	-0.5	4.6	V	
VI	DC input voltage		-2.0	5.75	V	
I _{OUT}	DC output current, per pin		-25	25	mA	
T _{STG}	Storage temperature	No bias	-65	150	°C	
T _{AMB}	Ambient temperature	Under bias	-65	135	°C	
ТJ	Junction temperature	Ceramic packages, under bias		150	°C	
		RQFP and BGA packages, under		135	°C	
		bias				

Table 2	Table 23. EPF10K50V & EPF10K130V Device Recommended Operating Conditions							
Symbol	Parameter	Conditions	Min	Max	Unit			
V _{CCINT}	Supply voltage for internal logic and input buffers	(3), (4)	3.00 (3.00)	3.60 (3.60)	V			
V _{CCIO}	Supply voltage for output buffers	(3), (4)	3.00 (3.00)	3.60 (3.60)	V			
VI	Input voltage	(5)	-0.5	5.75	V			
Vo	Output voltage		0	V _{CCIO}	V			
Τ _A	Ambient temperature	For commercial use	0	70	°C			
		For industrial use	-40	85	°C			
ΤJ	Operating temperature	For commercial use	0	85	°C			
		For industrial use	-40	100	°C			
t _R	Input rise time			40	ns			
t _F	Input fall time			40	ns			

Figure 21 shows the typical output drive characteristics of EPF10K50V and EPF10K130V devices.

Figure 21. Output Drive Characteristics of EPF10K50V & EPF10K130V Devices



Tables 26 through 31 provide information on absolute maximum ratings, recommended operating conditions, DC operating conditions, and capacitance for 3.3-V FLEX 10K devices.

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply voltage	With respect to ground (2)	-0.5	4.6	V
VI	DC input voltage		-2.0	5.75	V
I _{OUT}	DC output current, per pin		-25	25	mA
T _{STG}	Storage temperature	No bias	-65	150	°C
T _{AMB}	Ambient temperature	Under bias	-65	135	°C
TJ	Junction temperature	Ceramic packages, under bias		150	°C
		PQFP, TQFP, RQFP, and BGA packages, under bias		135	°C

Table 32. LE Timing Microparameters (Part 2 of 2) Note (1)						
Symbol	Parameter	Conditions				
t _{SU}	LE register setup time for data and enable signals before clock; LE register recovery time after asynchronous clear, preset, or load					
t _H	LE register hold time for data and enable signals after clock					
t _{PRE}	LE register preset delay					
t _{CLR}	LE register clear delay					
t _{CH}	Minimum clock high time from clock pin					
t _{CL}	Minimum clock low time from clock pin					

Symbol	Parameter	Conditions	
t _{IOD}	IOE data delay		
t _{IOC}	IOE register control signal delay		
t _{IOCO}	IOE register clock-to-output delay		
t _{IOCOMB}	IOE combinatorial delay		
t _{IOSU}	IOE register setup time for data and enable signals before clock; IOE register recovery time after asynchronous clear		
t _{IOH}	IOE register hold time for data and enable signals after clock		
t _{IOCLR}	IOE register clear time		
t _{OD1}	Output buffer and pad delay, slow slew rate = off, $V_{CCIO} = V_{CCINT}$	C1 = 35 pF (2)	
t _{OD2}	Output buffer and pad delay, slow slew rate = off, V_{CCIO} = low voltage	C1 = 35 pF (3)	
t _{OD3}	Output buffer and pad delay, slow slew rate = on	C1 = 35 pF (4)	
t _{XZ}	IOE output buffer disable delay		
t _{ZX1}	IOE output buffer enable delay, slow slew rate = off, $V_{CCIO} = V_{CCINT}$	C1 = 35 pF (2)	
t _{ZX2}	IOE output buffer enable delay, slow slew rate = off, V_{CCIO} = low voltage	C1 = 35 pF (3)	
t _{ZX3}	IOE output buffer enable delay, slow slew rate = on	C1 = 35 pF (4)	
t _{INREG}	IOE input pad and buffer to IOE register delay		
t _{IOFD}	IOE register feedback delay		
t _{INCOMB}	IOE input pad and buffer to FastTrack Interconnect delay		

Symbol	-2 Spee	d Grade	-3 Spee	d Grade	-4 Spee	ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t _{DIN2IOE}		6.6		7.3		8.8	ns
t _{DIN2LE}		4.2		4.8		6.0	ns
t _{DIN2DATA}		6.5		7.1		10.8	ns
t _{DCLK2IOE}		5.5		6.2		7.7	ns
t _{DCLK2LE}		4.2		4.8		6.0	ns
t _{SAMELAB}		0.4		0.4		0.5	ns
t _{SAMEROW}		4.8		4.9		5.5	ns
t _{SAMECOLUMN}		3.3		3.4		3.7	ns
t _{DIFFROW}		8.1		8.3		9.2	ns
t _{TWOROWS}		12.9		13.2		14.7	ns
t _{LEPERIPH}		5.5		5.7		6.5	ns
t _{LABCARRY}		0.8		0.9		1.1	ns
t _{LABCASC}		2.7		3.0		3.2	ns

Table 62. EPF10K70 Device External Timing Parameters Note (1)									
Symbol	-2 Spee	-2 Speed Grade		-3 Speed Grade		-4 Speed Grade			
	Min	Max	Min	Max	Min	Max			
t _{DRR}		17.2		19.1		24.2	ns		
t _{INSU} (2), (3)	6.6		7.3		8.0		ns		
t _{INH} (3)	0.0		0.0		0.0		ns		
t _{оитсо} (3)	2.0	9.9	2.0	11.1	2.0	14.3	ns		

Table 63. EPF10K70 Device External Bidirectional Timing Parameters

Note (1)

Symbol	-2 Spee	-2 Speed Grade		-3 Speed Grade		-4 Speed Grade	
	Min	Max	Min	Max	Min	Max	
t _{INSUBIDIR}	7.4		8.1		10.4		ns
t _{INHBIDIR}	0.0		0.0		0.0		ns
toutcobidir	2.0	9.9	2.0	11.1	2.0	14.3	ns
t _{XZBIDIR}		13.7		15.4		18.5	ns
t _{ZXBIDIR}		13.7		15.4		18.5	ns

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FLEX 10K Embedded Programmable Logic Device Family Data Sheet

Symbol	-3DX Spe	ed Grade	-3 Spee	ed Grade	-4 Spee	ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t _{IOD}		0.0		0.0		0.0	ns
t _{IOC}		0.5		0.5		0.7	ns
t _{IOCO}		0.4		0.4		0.9	ns
t _{IOCOMB}		0.0		0.0		0.0	ns
t _{IOSU}	5.5		5.5		6.7		ns
t _{IOH}	0.5		0.5		0.7		ns
t _{IOCLR}		0.7		0.7		1.6	ns
t _{OD1}		4.0		4.0		5.0	ns
t _{OD2}		6.3		6.3		7.3	ns
t _{OD3}		7.7		7.7		8.7	ns
t _{XZ}		6.2		6.2		6.8	ns
t _{ZX1}		6.2		6.2		6.8	ns
t _{ZX2}		8.5		8.5		9.1	ns
t _{ZX3}		9.9		9.9		10.5	ns
t _{INREG} without ClockLock or ClockBoost circuitry		9.0		9.0		10.5	ns
t _{INREG} with ClockLock or ClockBoost circuitry		3.0		-		-	ns
t _{IOFD}		8.1		8.1		10.3	ns
t _{INCOMB}		8.1		8.1		10.3	ns

Symbol	-3DX Spe	ed Grade	-3 Spee	ed Grade	-4 Spee	ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t _{EABAA}		13.7		13.7		17.0	ns
t _{EABRCCOMB}	13.7		13.7		17.0		ns
t _{EABRCREG}	9.7		9.7		11.9		ns
t _{EABWP}	5.8		5.8		7.2		ns
t _{EABWCCOMB}	7.3		7.3		9.0		ns
t _{EABWCREG}	13.0		13.0		16.0		ns
t _{EABDD}		10.0		10.0		12.5	ns
t _{EABDATACO}		2.0		2.0		3.4	ns
t _{EABDATASU}	5.3		5.3		5.6		ns
t _{EABDATAH}	0.0		0.0		0.0		ns
t _{EABWESU}	5.5		5.5		5.8		ns
t _{EABWEH}	0.0		0.0		0.0		ns
t _{EABWDSU}	5.5		5.5		5.8		ns
t _{EABWDH}	0.0		0.0		0.0		ns
t _{EABWASU}	2.1		2.1		2.7		ns
t _{EABWAH}	0.0		0.0		0.0		ns
t _{EABWO}		9.5		9.5		11.8	ns

Symbol	-1 Spee	d Grade	-2 Spee	d Grade	-3 Spee	d Grade	-4 Spee	d Grade	Unit
	Min	Max	Min	Max	Min	Max	Min	Max	
t _{EABAA}		9.5		13.6		16.5		20.8	ns
t _{EABRCCOMB}	9.5		13.6		16.5		20.8		ns
t _{EABRCREG}	6.1		8.8		10.8		13.4		ns
t _{EABWP}	6.0		4.9		6.0		7.4		ns
t _{EABWCCOMB}	6.2		6.1		7.5		9.2		ns
t _{EABWCREG}	12.0		11.6		14.2		17.4		ns
t _{EABDD}		6.8		9.7		11.8		14.9	ns
t _{EABDATACO}		1.0		1.4		1.8		2.2	ns
t _{EABDATASU}	5.3		4.6		5.6		6.9		ns
t _{EABDATAH}	0.0		0.0		0.0		0.0		ns
t _{EABWESU}	4.4		4.8		5.8		7.2		ns
t _{EABWEH}	0.0		0.0		0.0		0.0		ns
t _{EABWDSU}	1.8		1.1		1.4		2.1		ns
t _{EABWDH}	0.0		0.0		0.0		0.0		ns
t _{EABWASU}	4.5		4.6		5.6		7.4		ns
t _{EABWAH}	0.0		0.0		0.0		0.0		ns
t _{EABWO}		5.1		9.4		11.4		14.0	ns

Symbol	-2 Spee	d Grade	-3 Spec	ed Grade	-4 Spee	ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t _{IOD}		1.3		1.6		2.0	ns
t _{IOC}		0.4		0.5		0.7	ns
t _{IOCO}		0.3		0.4		0.5	ns
t _{IOCOMB}		0.0		0.0		0.0	ns
t _{IOSU}	2.6		3.3		3.8		ns
t _{IOH}	0.0		0.0		0.0		ns
t _{IOCLR}		1.7		2.2		2.7	ns
t _{OD1}		3.5		4.4		5.0	ns
t _{OD2}		-		-		-	ns
t _{OD3}		8.2		8.1		9.7	ns
t _{XZ}		4.9		6.3		7.4	ns
t _{ZX1}		4.9		6.3		7.4	ns
t _{ZX2}		_		-		-	ns
t _{ZX3}		9.6		10.0		12.1	ns
t _{INREG}		7.9		10.0		12.6	ns
t _{IOFD}		6.2		7.9		9.9	ns
t _{INCOMB}		6.2		7.9		9.9	ns

Symbol	-2 Spee	d Grade	-3 Spee	d Grade	-4 Spee	ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t _{EABAA}		11.2		14.2		14.2	ns
t _{EABRCCOMB}	11.1		14.2		14.2		ns
t _{EABRCREG}	8.5		10.8		10.8		ns
t _{EABWP}	3.7		4.7		4.7		ns
t _{EABWCCOMB}	7.6		9.7		9.7		ns
t _{EABWCREG}	14.0		17.8		17.8		ns
t _{EABDD}		11.1		14.2		14.2	ns
t _{EABDATACO}		3.6		4.6		4.6	ns
t _{EABDATASU}	4.4		5.6		5.6		ns
t _{EABDATAH}	0.0		0.0		0.0		ns
t _{EABWESU}	4.4		5.6		5.6		ns
t _{EABWEH}	0.0		0.0		0.0		ns
t _{EABWDSU}	4.6		5.9		5.9		ns
t _{EABWDH}	0.0		0.0		0.0		ns
t _{EABWASU}	3.9		5.0		5.0		ns
t _{EABWAH}	0.0		0.0		0.0		ns
t _{EABWO}		11.1		14.2		14.2	ns

Symbol	-1 Snoo	d Grade	-2 Spee	d Grado	-3 Spee	d Grado	Unit
Symbol			-		-		Unit
	Min	Max	Min	Max	Min	Max	
t _{EABAA}		8.1		9.8		13.1	ns
t _{EABRCCOMB}	8.1		9.8		13.1		ns
t _{EABRCREG}	5.8		6.9		9.3		ns
t _{EABWP}	2.0		2.4		3.2		ns
t _{EABWCCOMB}	3.5		4.2		5.6		ns
t _{EABWCREG}	9.4		11.2		14.8		ns
t _{EABDD}		6.9		8.3		11.0	ns
t _{EABDATACO}		1.3		1.5		2.0	ns
t _{EABDATASU}	2.4		3.0		3.9		ns
t _{EABDATAH}	0.0		0.0		0.0		ns
t _{EABWESU}	4.1		4.9		6.5		ns
t _{EABWEH}	0.0		0.0		0.0		ns
t _{EABWDSU}	1.4		1.6		2.2		ns
t _{EABWDH}	0.0		0.0		0.0		ns
t _{EABWASU}	2.5		3.0		4.1		ns
t _{EABWAH}	0.0		0.0		0.0		ns
t _{EABWO}		6.2		7.5		9.9	ns

Symbol	-1 Snee	d Grade	-2 Snee	d Grade	-3 Snee	d Grade	Unit
oy moor	Min	Max	Min	Max	Min	Max	
t _{EABAA}		6.8		7.8		9.2	ns
t _{EABRCCOMB}	6.8		7.8		9.2		ns
t _{EABRCREG}	5.4		6.2		7.4		ns
t _{EABWP}	3.2		3.7		4.4		ns
t _{EABWCCOMB}	3.4		3.9		4.7		ns
t _{EABWCREG}	9.4		10.8		12.8		ns
t _{EABDD}		6.1		6.9		8.2	ns
t _{EABDATACO}		2.1		2.3		2.9	ns
t _{EABDATASU}	3.7		4.3		5.1		ns
t _{EABDATAH}	0.0		0.0		0.0		ns
t _{EABWESU}	2.8		3.3		3.8		ns
t _{EABWEH}	0.0		0.0		0.0		ns
t _{EABWDSU}	3.4		4.0		4.6		ns
t _{EABWDH}	0.0		0.0		0.0		ns
t _{EABWASU}	1.9		2.3		2.6		ns
t _{EABWAH}	0.0		0.0		0.0		ns
t _{EABWO}		5.1		5.7		6.9	ns

Symbol	-1 Spee	d Grade	-2 Spee	d Grade	-3 Spee	ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t _{DIN2IOE}		4.8		5.4		6.0	ns
t _{DIN2LE}		2.0		2.4		2.7	ns
t _{DIN2DATA}		2.4		2.7		2.9	ns
t _{DCLK2IOE}		2.6		3.0		3.5	ns
t _{DCLK2LE}		2.0		2.4		2.7	ns
t _{SAMELAB}		0.1		0.1		0.1	ns
t _{SAMEROW}		1.5		1.7		1.9	ns
t _{SAME} COLUMN		5.5		6.5		7.4	ns
t _{DIFFROW}		7.0		8.2		9.3	ns
t _{TWOROWS}		8.5		9.9		11.2	ns
t _{LEPERIPH}		3.9		4.2		4.5	ns
t _{LABCARRY}		0.2		0.2		0.3	ns
t _{LABCASC}		0.4		0.5		0.6	ns

Table 104. EPF10K100A Device External Timing Parameters Note (1)

Symbol	-1 Spee	ed Grade	-2 Spee	ed Grade	-3 Spee	d Grade	Unit
	Min	Max	Min	Max	Min	Max	
t _{DRR}		12.5		14.5		17.0	ns
t _{INSU} (2), (3)	3.7		4.5		5.1		ns
t _{INH} (3)	0.0		0.0		0.0		ns
t _{оитсо} (3)	2.0	5.3	2.0	6.1	2.0	7.2	ns

7.4

Table 105. EPF10K100A Device External Bidirectional Timing Parameters Note (1)								
Symbol	-1 Spec	ed Grade	-2 Spee	ed Grade	-3 Speed Grade		Unit	
	Min	Max	Min	Max	Min	Max		
t _{INSUBIDIR}	4.9		5.8		6.8		ns	
t _{INHBIDIR}	0.0		0.0		0.0		ns	
toutcobidir	2.0	5.3	2.0	6.1	2.0	7.2	ns	
t _{XZBIDIR}		7.4		8.6		10.1	ns	

8.6

t_{ZXBIDIR}

ns

10.1